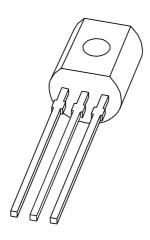
DISCRETE SEMICONDUCTORS

DATA SHEET



2N3904 NPN switching transistor

Product specification Supersedes data of 1999 Apr 23 2004 Oct 11





NPN switching transistor

2N3904

FEATURES

- Low current (max. 200 mA)
- Low voltage (max. 40 V).

APPLICATIONS

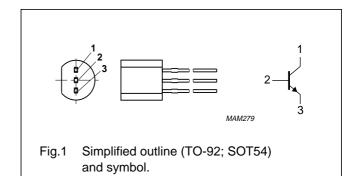
• High-speed switching.

DESCRIPTION

NPN switching transistor in a TO-92; SOT54 plastic package. PNP complement: 2N3906.

PINNING

PIN	DESCRIPTION
1	collector
2	base
3	emitter



ORDERING INFORMATION

TYPE NUMBER		PACKAGE	
TIPE NUMBER	NAME	DESCRIPTION	VERSION
2N3904	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	60	V
V _{CEO}	collector-emitter voltage	open base	_	40	V
V _{EBO}	emitter-base voltage	open collector	_	6	V
I _C	collector current (DC)		_	200	mA
I _{CM}	peak collector current		_	300	mA
I _{BM}	peak base current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C.

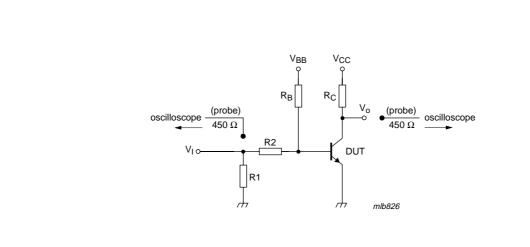
SYMBOL	PARAMETER	R CONDITIONS			UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0 A	_	50	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = 6 V; I _C = 0 A	_	50	nA
h _{FE}	DC current gain	V _{CE} = 1 V; note 1			
		I _C = 0.1 mA	60	_	
		I _C = 1 mA	80	_	
		I _C = 10 mA	100	300	
		I _C = 50 mA	60	_	
		I _C = 100 mA	30	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 1 mA; note 1	_	200	mV
		$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	200	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 1 \text{ mA}; \text{ note 1}$	_	850	mV
		$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	950	mV
C _c	collector capacitance	$V_{CB} = 5 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	_	4	pF
C _e	emitter capacitance	$V_{EB} = 500 \text{ mV}; I_C = I_C = 0 \text{ A}; f = 1 \text{ MHz}$	_	8	pF
f _T	transition frequency	V _{CE} = 20 V; I _C = 10 mA; f = 100 MHz	300	_	MHz
F	noise figure	$V_{CE} = 5 \text{ V; } I_{C} = 100 \mu\text{A; } R_{S} = 1 k\Omega;$	_	5	dB
Switching t	imes (between 10 % and 90 % level	ls); see Fig.2			
t _{on}	turn-on time	I _{Con} = 10 mA; I _{Bon} = 1 mA;	_	65	ns
t _d	delay time	I _{Boff} = −1 mA	_	35	ns
t _r	rise time		_	35	ns
t _{off}	turn-off time		_	240	ns
t _s	storage time		_	200	ns
t _f	fall time		_	50	ns

Note

1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

NPN switching transistor

2N3904



 V_i = 5 V; T = 500 $\mu s;$ t_p = 10 $\mu s;$ t_r = $t_f \leq 3$ ns.

R1 = 56 Ω ; R2 = 2.5 k Ω ; R_B = 3.9 k Ω ; R_C = 270 Ω .

 $V_{BB} = -1.9 \text{ V}; V_{CC} = 3 \text{ V}.$

Oscilloscope input impedance $Z_i = 50 \ \Omega$.

Fig.2 Test circuit for switching times.

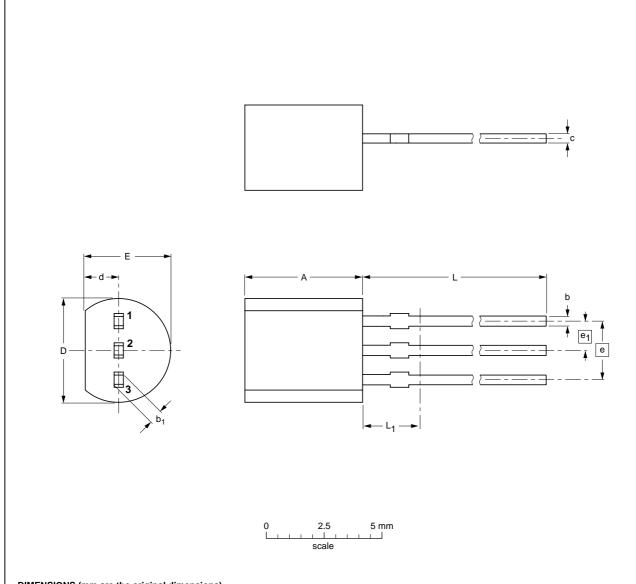
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE	LINE REFERENCES					ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			97-02-28 04-06-28

NPN switching transistor

2N3904

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
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